

### **FJPF13007**

### **High Voltage Switch Mode Application**

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



1.Base 2.Collector 3.Emitter

### **NPN Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector- Base Voltage	700	V	
V <sub>CEO</sub>	Collector- Emitter Voltage	400	V	
V <sub>EBO</sub>	Emitter- Base Voltage	9	V	
I <sub>C</sub>	Collector Current (DC)	8	А	
I <sub>CP</sub>	Collector Current (Pulse)	16	Α	
I <sub>B</sub>	Base Current	4	Α	
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W	
TJ	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C	

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Base Breakdown Voltage	$I_C = 10 \text{mA}, I_B = 0$	400			V
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	mA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 2A$	8		60	
		$V_{CE} = 5V, I_{C} = 5A$	5		30	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.4A$			1	V
		$I_C = 5A, I_B = 1A$	197		2	V
		$I_{C} = 8A, I_{B} = 2A$		87	3	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.4A$		Total V	1.2	V
		$I_C = 5A, I_B = 1A$			1.6	V
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10V$ , $f = 0.1MHz$		110		pF
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$	4			MH
t <sub>ON</sub>	Turn On Time	$V_{CC} = 125V, I_{C} = 5A$			1.6	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 1A$			3	μs
t⊨	Fall Time	$R_L = 50\Omega$			0.7	μs

### h<sub>FE</sub> Classification

Classification	R(H1)	O(H2)
h <sub>FE1</sub>	15 ~ 28	26 ~ 39

### **Typical Characteristics**

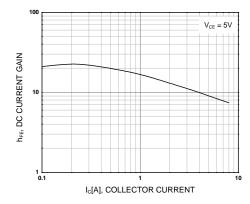


Figure 1. DC current Gain

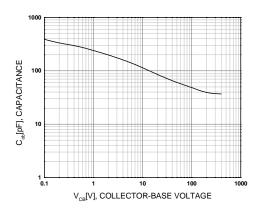


Figure 3. Collector Output Capacitance

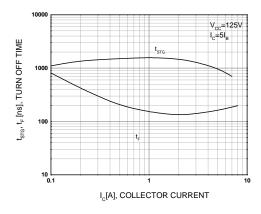


Figure 5. Turn Off Time

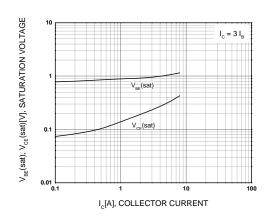


Figure 2. Saturation Voltage

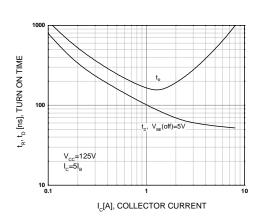


Figure 4. Turn On Time

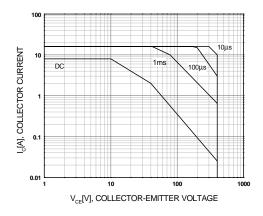


Figure 6. Forward Biased Safe Operating Area

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### **Typical Characteristics** (Continued)

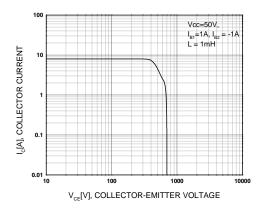


Figure 7. Reverse Biased Safe Operating Area

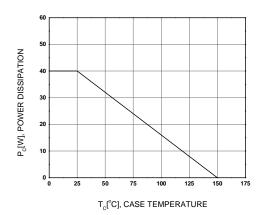
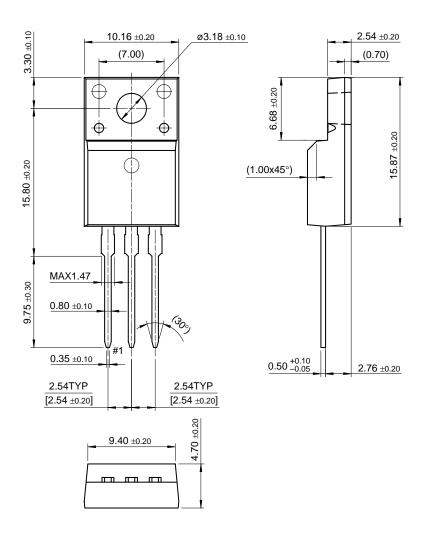


Figure 8. Power Derating

## **Package Dimensions**

### TO-220F



Dimensions in Millimeters

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